



## NCE P-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE01P30 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

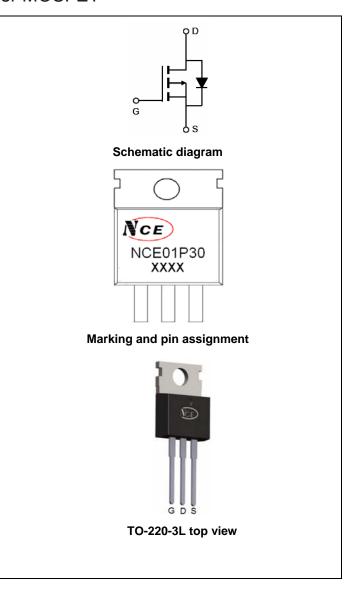
- $V_{DS}$  =-100V, $I_{D}$  =-30A  $R_{DS(ON)}$  <58mΩ @  $V_{GS}$ =-10V (Typ:50mΩ)
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

#### **Application**

Portable equipment and battery powered systems

100% UIS TESTED!

100% ΔVds TESTED!



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01P30	NCE01P30	TO-220-3L	-	-	-

#### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-100	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	-30	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	-21	Α
Pulsed Drain Current	I <sub>DM</sub>	-140	Α
Maximum Power Dissipation	P <sub>D</sub>	120	W
Derating factor		0.8	W/℃
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$



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## NCE01P30

#### **Thermal Characteristic**

## Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Symbol Condition		Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-1.5	-1.9	-3	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-15A	-	50	58	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-50V,I <sub>D</sub> =-10A	5	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	)/ OF)/)/ O)/	-	2700	-	PF
Output Capacitance	Coss	$V_{DS}$ =-25V, $V_{GS}$ =0V, F=1.0MHz	-	790	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIHZ	-	450	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	17	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =-50V,I <sub>D</sub> =-15A	-	80	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =-10V, $R_{GEN}$ =9.1 $\Omega$	-	45	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	65	-	nS
Total Gate Charge	Qg	)/ 50)/I 45A	-	90	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-50V, $I_{D}$ =-15A, $V_{GS}$ =-10V	-	15	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	35	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =-10A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	-30	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =-15A	-	90	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	70	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

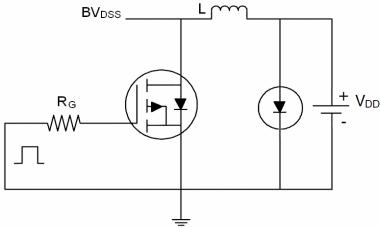
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=-50V,V<sub>G</sub>=-10V,L=0.5mH,Rg=25 $\Omega$

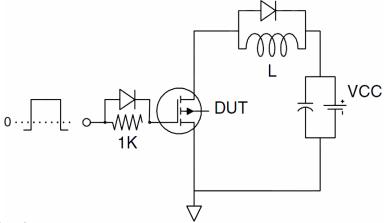


## **Test Circuit**

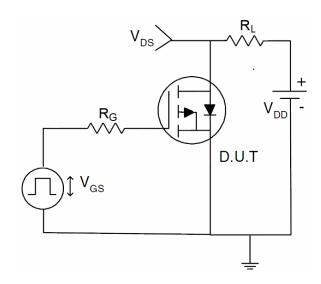
## 1) E<sub>AS</sub> Test Circuit



## 2) Gate Charge Test Circuit

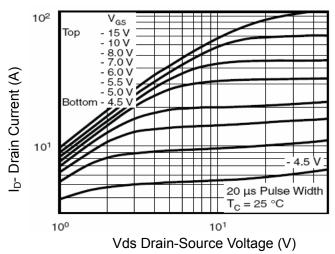


## 3) Switch Time Test Circuit

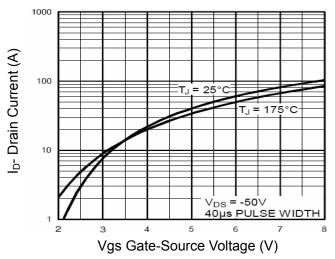




## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

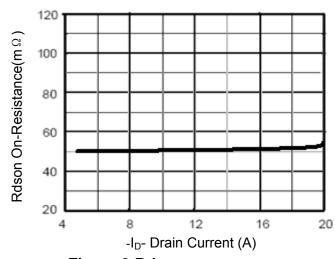


Figure 3 Rdson- Drain Current

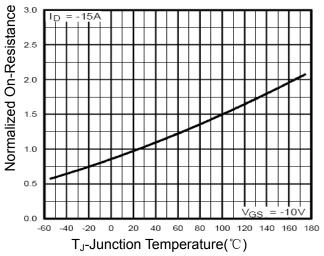
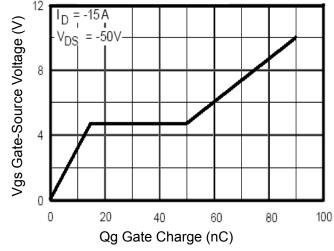


Figure 4 Rdson-JunctionTemperature



**Figure 5 Gate Charge** 

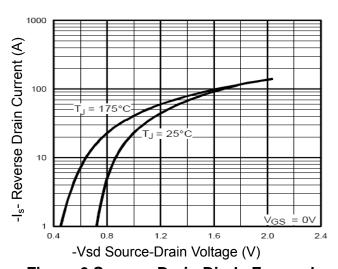


Figure 6 Source- Drain Diode Forward



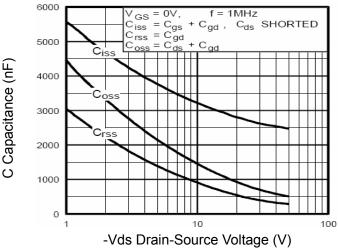
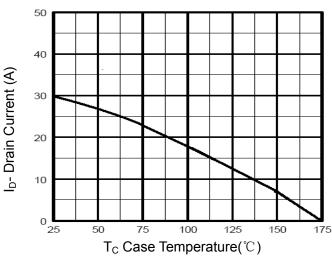


Figure 7 Capacitance vs Vds



**Figure 9 Drain Current vs Case Temperature** 

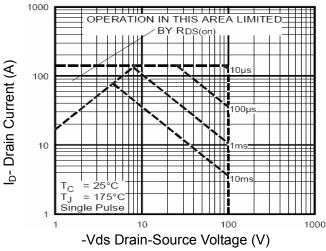


Figure 8 Safe Operation Area

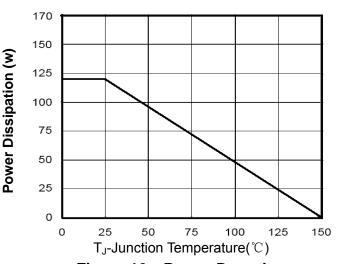
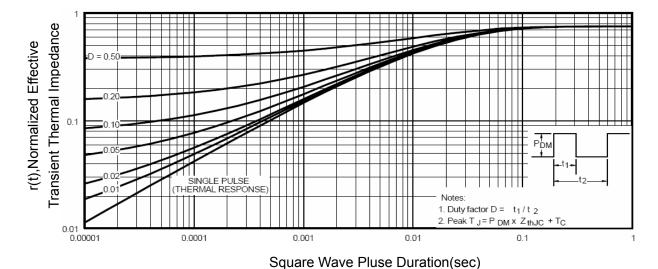


Figure 10 Power De-rating



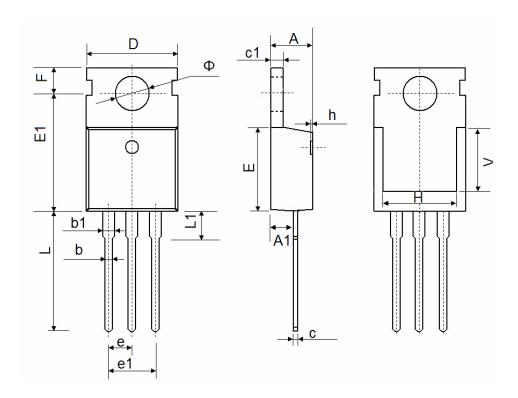
**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# NCE01P30

**Pb Free Product** 

## **TO-220-3L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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